Soliton like wave packets in quantum wires

P. Singha Deo

Unit for Nano Science and Technology, S.N.Bose National Centre for Basic Sciences,

JD Block, Sector III, Salt Lake City, Kolkata 98, India.

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At a Fano resonance in a quantum wire there is strong quantum mechanical back-scattering. When identical wave packets are incident along all possible modes of incidence, each wave packet is strongly scattered. The scattered wave packets compensate each other in such a way that the outgoing wave packets are similar to the incoming wave packets. This is as if the wave packets are not scattered and not dispersed. This typically happens for the kink-antikink solution of the Sine-G ordon model. As a result of such non-dispersive behavior, the derivation of semiclassical form ulas like the Friedel sum rule and the W igner delay time are exact at Fano resonance. For a single channel quantum wire this is true for any potential that exhibit a Fano resonance. For a multichannel quantum wire we give an easy prescription to check for a given potential, if this is true. W e also show that validity of the Friedel sum rule may or may not be related to the conservation of charge. If there are evanescent modes then even when charge is conserved, Friedel sum rule may break down away from the Fano resonances.

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I. IN TRODUCTION

The Landauer-Buttiker approach to mesoscopic physics is rather novel. One of the great success of this approach is the Landauer-Buttiker conductance form ula. To understand this approach further and the key to generalize this approach is the Friedel sum rule (FSR). It has been the subject of much study recently. W hile exact proofs can be given for bulk samples [1, 2, 3], in low dim ensional system s som e attem pts to derive it ignore the e ects of the leads [4, 5]. Buttiker and his co-workers, emphasize the e ects of the leads and nd a correction term to the FSR [6, 7]. They state that leads can result in non-conservation of charge in quantum regimes and in such regimes FSR will break down. When the system is in the W KB lim it, then charge is conserved and FSR works very well. Recent explicit calculations [8] for an impurity in a quantum wire contradicted this result. A single attractive in purity in a quantum wire can produce m any resonant states that can all be classi ed as Fano resonances [9, 10]. Such an impurity in a quantum wire has attracted m any theoretical investigation [11]. Ref. [8]

nds that the Friedel sum rule is exact at the Fano resonance which is a pure quantum interference phenom enon (and not a W KB regim e), and very bad in the regim es away from the Fano resonance (that are in the W KB regim e). Ref. [12] shows that other sem iclassical form ulas like the W igner delay time (W D T) also become exact at the Fano resonance. An analysis of charge conservation and the origin of sem iclassical behavior in a quantum regim e is m issing in Refs. [8, 12]. In this work we show that there is no connection between charge conservation and validity of FSR in the sense that FSR can be violated even when charge is conserved. W e shall also show that although such an impurity in a quantum wire give strong back scattering that is quantum mechanical in nature, such scattering do not disperse a wave packet. W e shall also show that this explains why sem i-classical theories are exact in a purely quantum mechanical regime.

W hen one considers transport in mesoscopic systems then one typically considers a system as shown in Fig 1. The system between the points A and B is a grand canonical system coupled to reservoirs. The way we study grand canonical systems in text books is that the reservoir H am iltonian and the system H am iltonian can be decoupled. This allows one to construct a grand canonical partition function. But m esoscopic samples are so sm all that the actual modeling of the coupling to the reservoirs is necessary [13, 14, 15, 16]. The leads (here we show only two leads but there can be many) are ideal wires that connect the system to the reservoirs. They in ject and absorb electrons and also de ne the correct boundary conditions for the system . The region between A and B is an elastic scatterer. A particle injected by reservoir 1 will freely propagate along lead 1 and will be incident on the scatterer between A and B. The re ected part will be absorbed by reservoir 1 and the transm itted part will be absorbed by reservoir 2. The absorbed electrons are com pletely therm alized inside the reservoirs and their coherence is destroyed. P hase shifts are de ned with respect to points A and B and not with respect to

1 [6]. Density of states (DOS) is also the local density of states (LDOS) integrated between the points A and B [6]. The scattering problem is completely de ned with the points A and B [6] provided the total charge in the region between A and B (or the integrated LDOS in the region between A and B) is conserved. The region outside that can be param etrized with chem ical potential () and tem perature (T). If and T are the same for the two reservoirs, then we get an equilibrium situation, and if they are di erent then we get non-equilibrium situation. A ll this will become explicit in our model calculation.

II. THE SCATTER ING SOLUTION

As a simple realization of such a system (as shown in Fig. 1) in one dimension (1D) we can consider a double delta function potential in 1D between x = 1 and x = 1 (see Fig. 2). The free regions x < 1 and x > 1 are the leads. For a symmetric scatterer in 1D, the scattering matrix is

$$S = \begin{array}{c} R & T \\ T & R \end{array}$$
(1)

where R is the re ection amplitude and T is the transm ission amplitude of the scatterer.

If we consider a two channel quantum wire with a delta function potential. The scattering matrix will be 4X 4 as shown below.

$$S = \begin{cases} 2 & R_{11} & R_{12} & T_{11} & T_{12} & 3 \\ 6 & R_{21} & R_{22} & T_{21} & T_{22} & 7 \\ T_{11} & T_{12} & R_{11} & R_{12} \\ T_{21} & T_{22} & R_{21} & R_{22} \end{cases}$$
(2)

We are using a notation that $S_{11} = R_{11}$ as it is a reection am plitude for an electron incident along the rst transverse mode from the left lead and scattered back to the rst transverse mode in the left lead. Sim ilarly, $S_{12} = R_{12}$ as it is a rejection am plitude for an electron incident along the rst transverse mode from the left lead and scattered back to the second transverse mode in the left lead. Sim ilarly, $S_{13} = T_{11}$ as it is a transmission am plitude for an electron incident along the rst transverse mode from the left lead and scattered forward to the rst transverse mode in the right lead. O ne can easily understand the rest. O ne can solve the scattering problem to nd that for and taking values 1 or 2,

$$R = \frac{i}{2d k k}$$
(3)

If € then

$$I = \frac{i}{2d k k}$$
(4)

If = then

$$T = 1 + R$$
 (5)

Here

$$= \frac{2m}{2} \sin \left[\frac{1}{w} (y_j + w = 2) \right] \sin \left[\frac{1}{w} (y_j + w = 2) \right]$$
(6)

$$d = 1 + \frac{1}{2} + i \frac{1}{2k}$$
(7)

$$= \frac{2m}{2} S \ln \left[\frac{1}{w} (y_{j} + w = 2)\right] S \ln \left[\frac{1}{w} (y_{j} + w = 2)\right]$$
(8)

can take any integer value greater than 2 (i.e., $= 3, 4, 5, \ldots$). is the strength of the delta function potential situated at x = 0 and $y = y_j$. m is particle mass and w is the width of the quantum wire. ^{2m}/₂ (E $\frac{2}{w^2}$) is the wave vector for the 1st prop $k_1 =$ $\frac{4^{2}}{2}$) is the wave vector 2m (E agating channel. $k_2 =$ 2m (for the 2nd propagating channel. E) is the wave vector for the the vanescent channel. E is the incident energy. The nth quasi bound state or the Fano resonance occur at energies that satisfy the follow ing equation

$$1 + \prod_{n=1}^{n=1} \frac{1}{2} = 0$$
 (9)

At such an energy, there will be a large am ount of charge localized around the impurity and decaying away from the impurity. One can de ne the points A and B as the cut o points beyond which the localized charge has decayed to negligible values. Also in real systems will have some cut o that can have several physical origins like decoherence or work function of the quantum wire. The thin jectivity at a point q (x;y;z) is due to the incident electron of velocity v (or v). It is de ned as

Х

$$(q) = \frac{1}{h j r j} (q) f$$
(10)

where, h is Plank's constant, $v = \frac{-k}{m}$, k is incident wave vector, m is particle mass, q represents coordinate and ⁽⁾(q) is quantum mechanical wave function due to unit current incident in the th channel. (q) is known as the partial local density of states (PLDOS). For di erent possible values of incident wave vector, we get di erent injectivities. Sum m ing up for all the injectivities we get the local density of states (LDOS). Integrating LDOS over entire spatial coordinates we get DOS. So DOS will be

$$(E) = \frac{X^{M} Z_{1}}{\sum_{j=1}^{M} \frac{1}{h j y_{j}} j^{(j)}(q) j^{2} dq}$$
(11)

And

^{GC} (E) =
$$\frac{X^{A} Z_{B}}{\prod_{a=1}^{A} h_{j} j_{j}} (1) (q) f dq$$
 (12)

Here su $x \in C$ stands for \grand canonical". Here M is the total num ber of incident channels possible.

III. FRIEDEL SUM RULE (FSR)

If the charge in the region between A and B is conserved then the scattering problem is completely de ned with respect to the points A and B.FSR suggests that the DOS in Eq. 12 can be calculated from S matrix, without any know ledge of the () (q) as the S m atrix elem ents can be determ ined experim entally [17, 18] as well as theoretically [19, 20].

The FSR can be stated as [8, 21]

$$\frac{d_{f}}{dE} \begin{bmatrix} G^{C}(E) & G^{C}(E) \end{bmatrix}$$
(13)

where

$$f = \frac{1}{2i} \log (0 \text{ et}[S])$$
 (14)

S is the scattering matrix of a system and E is incident electron energy. GC (E) is integrated LDOS of a system in presence of scatterer as de ned in Eq. 12 and $_{0}^{GC}$ (E) is integrated LDOS of the same system in absence of scatterer, which naturally requires that in purity scattering conserves the total num ber of states in the system or the total charge in the system (or else need not be related to $_0$ at all). In Eq. 13 we have used an approximate equality as there will be a correction term which we will discuss later. The beauty of Eq. 13 is its universality. At any resonance (or quasibound state) $\begin{bmatrix} GC \\ C \end{bmatrix}$ change by unity and hence f will change by . Moreover, $\frac{d_{f}}{d\pi}$ can be determined from asymptotic wave function (x ! 1) and so one can completely avoid integrating the LDOS to nd the DOS.

The purpose of this section is to explain the discrepancy observed in Ref. [8] about the FSR. Namely the FSR becomes exact in a purely quantum regime like the Fano regime and bad away from the Fano regime. According to our previous understanding, it should have been the opposite. Such an explanation requires a detailed analysis of charge conservation and quantum behavior as follows. A physical origin of such a behavior will become clear in the next section.

To understand where FSR may go wrong, we rst inspect a derivation of the FSR [21]. We present it for 1D as the steps can be repeated for Q 1D . Suppose there is an extended potential V (x) (to be dimensionally correct in the subsequent analysis, V (x) eV (x), where e is electronic charge). A ssum ing that S ; (E;V(x)) is analytic, we can make an expansion as

$$S ; (E; V(x) + V(x)) = S ; (E; V(x)) +$$

$$\int_{1}^{Z_{1}} dx^{0} \left[\frac{@S_{i}; (E_{i}; V_{i}(x^{0}))}{@V_{i}(x^{0})} V_{i}(x^{0}) \right] + \dots$$
(15)

Essentially this means breaking up the increment V(x)(although an in nitesim alperturbation, it is an extended potential) into many local increments V (x⁰) and integrating the e ect of all these local increments. V(x) is therefore a delta function potential at x^0 . Now without any loss of generality, we can say that $V(x) = V_0$ for all x. In other words V (x) is a constant potential. Since $V(x) = V_0$ for all x, the local perturbation $V(x^0)$ is

also equal to Vo, num erically. One has to rem ember that the two perturbations V (x) = V₀ and V (x⁰) = V₀ are actually di erent. One of them is a global perturbation or an extended perturbation while the latter is a local perturbation. However, for V_0 ! 0, one can neglect this di erence between them to write

$$\frac{S ; (E; V(x) + V_0) S ; (E; V(x))}{V_0}$$

$$\frac{Z _1}{dx^0 [\frac{@S ; (E; V(x^0))}{@V(x^0)}]}$$
(16)

Note that now we have an approxim ate equality and this can be further justi ed by explicit calculations as shown below.

Now one may propose that instead of increasing the potential everywhere by an in nitesim alam ount V_0 , one m ay keep the potential constant and instead decrease the incident energy by $E = V_0 \cdot T$ hus

$$\frac{S; (E E; V(x)) S; (E; V(x))}{E} = \frac{S; (E; V(x) + V(x)) S; (E; V(x))}{V_0}$$

$$\frac{Z_1}{1} dx^0 [\frac{(e_S; (E; V(x^0)))}{(e_V(x^0))}]$$
(17)

0 ne can prove that [21]

$$\frac{1}{4 i} (S^{Y} \frac{@S}{@V (x^{0})} H C) = (x)$$
(18)

where R. is the PLDOS. PDOS is therefore 0 (E) = (x)dx. One can take any potential in 1D and 1 check that this equation is exact as done in Ref. [6]. Therefore, from Eqs. 17 and 18,

$$\frac{1}{4 i}$$
 (S^Y $\frac{dS}{dE}$ HC) ⁰ (E) (19)

This on sum ming over and and further simpli cation gives

$$\frac{1}{2idE} \log (Det[S]) \quad [(E)_{0}(E)] \quad (20)$$

Thus we have derived FSR. Replacing $dx^{0 \frac{0}{2}S}_{\frac{0}{2}V(x^0)}$ by $\frac{-\frac{0}{2}S}{\frac{0}{2}E}$ is an approximation. Thus, $\frac{d_f}{dE}$ is not exactly equal to [(E)) 0 (E)] and so naturally one can expect that $\frac{d_f}{dE}$ is also not exactly equalto $\begin{bmatrix} G^{C}(E) & G^{C}(E) \end{bmatrix}$. In fact [7],

$$\frac{d_{f}}{dE} = \begin{bmatrix} G^{C}(E) & G^{C}(E) \end{bmatrix} \text{ Im } (R_{LL} + R_{RR}) = 4E$$
(21)

We have used su xes LL' and RR', instead of and . The reasons are obvious as R_{LL} is for the electrons incident from the left and re ected back to the left lead, while R_{RR} is for the electrons incident from the right and re ected back to the right lead. One may consider Eq. 21 as a new FSR but the correction term [Im (R_{LL} + R_{RR})=4E] is not very universal. It can be di erent for di erent kinds of resonances. Secondly, in quasi 1D we will see that this correction term will also depend on internal details of the potential and can vary from sam ple to sam ple.

So the correction term is Im (R $_{\rm L\,L}$ + R $_{\rm R\,R}$)=4E . Ref. [7] and others assume that this term is due to the nonconservation of charge in the system . They assume (see Eqs. 11 and 12 in Ref [7]) that this term can be related to self energy due to the escape probability of an electron in to the leads. So according to [7], in quantum regimes, this term can be large. An essential component of this work is to establish that this correction term is not due to non-conservation of charge. A though in 1D, 2D and 3D the correction term is large when the escape probability to the leads is large (that is charge is not conserved in the grand canonical system) and vice versa, this is not true in Q1D.We show below that the correction term can be large in Q1D even when charge is conserved and also the correction term can be zero in the Fano regime which is a quantum regime.

It is shown in the appendix that

$$[((E)_{0}(E)] = \begin{bmatrix} GC \\ C \end{bmatrix} \begin{bmatrix} GC \\ C \end{bmatrix} = \begin{bmatrix} GC \\ C \end{bmatrix}$$

$$\frac{\sin [2k1]}{k} (R_{LL} + R_{RR}) + \frac{\cos [2k1]}{k} (iR_{LL} - iR_{RR})$$
 (22)

This has two im plications. First is that since $\begin{bmatrix} G^{C} \\ E \end{bmatrix}$ $\begin{bmatrix} G^{C} \\ E \end{bmatrix}$ Im $(R_{LL} + R_{RR})=4E \in [((E) _{0} (E)], \text{ it follows from Eq. 21 that}$

$$\frac{d_{f}}{dE} \notin [(E)_{0}(E)]$$
 (23)

It can only be an approximate equality as shown before. The second implication is that the correction term

Im $(R_{LL} + R_{RR})=4E$ is not due to the lack of charge conservation. This is explained below. When we integrate over all energy then we get that the RHS of Eq. 22 goes as (k). The global charge has to be conserved, in plying 1 dE [((E) 0(E)] = 0. Hence from Eq. $22, \frac{R_1}{1}$ dE [((E) 0(E)] goes as (k). Since only positive energy states are propagating states that we are interested in, one can always take the integration over E in the positive energy regine instead of taking it from 1 to 1. As k = 0 is a non-propagating state, in the propagating regime $dE [((G^{C})(E)) = 0, S^{(G^{C})}(E)] = 0.$ So charge is conserved in the grand canonical system. So the correction term in Eq. 21 is arising due to the error involved in the substitution in Eq. 17 and has nothing to do with charge conservation. It is just an error due to an approximation in the algebra.

A lthough in the appendix we have considered a 1D system, all the steps can be repeated for a single channel Q1D system. Only the expressions for $R_{\rm LL}$ and $R_{\rm RR}$ will be dimensional density of $k = \frac{2m_{\odot}}{2} (E = E_1)$. So for a single channel quantum wire,

$$\frac{d_{f}}{dE} = \begin{bmatrix} GC \\ E \end{bmatrix} = \begin{bmatrix} GC \\ 0 \end{bmatrix} = \begin{bmatrix} GC \\ 0 \end{bmatrix} = \begin{bmatrix} GC \\ 0 \end{bmatrix} = \begin{bmatrix} R_{LL} + R_{RR} \\ 4 \\ E \\ E_{1} \end{bmatrix}$$
(24)

First of all note the presence of sample speci c parameter E_1 in the correction term that was ignored in Ref. [7]. This equation is the same whether evanescent modes are present or not present. However, only the expressions for $R_{\rm LL}$ and $R_{\rm RR}$ changes completely in presence and absence of evanescent modes. From Eq. 3

$$\operatorname{Im} \left[\mathbb{R}_{LL} + \mathbb{R}_{RR} \right] = \frac{\frac{11}{k_{\rm B}} \left(1 + \frac{P}{n > 1} \frac{1}{2} \right)}{\left(1 + \frac{P}{n > 1} \frac{1}{2} \right)^2 + \left(\frac{11}{2k_1} \right)^2} \quad (25)$$

For a delta function potential in 1D,

Im
$$[R_{LL} + R_{RR}] = \frac{\frac{1D}{k_1}}{1 + (\frac{1D}{2k_1})^2}$$
 (26)

where $_{1D} = \frac{2m}{2}$. In comparison with the 1D case, the only di erence in quasione dimension (Q 1D) (compare Eqs. 25 and 26) is the term

If we remove this term then the correction term is negligible for $k_1 > 1_1$ which is the sem i-classical regime. \mathcal{G} om plications in Q1D arise because_pof the series term $_{n>1}$ $\frac{1}{2}$. Even for $k_1 < _{11}$, (1 + $_{n>1}$ $\frac{1}{2}$) can becom e zero and then the correction term can becom e 0 in a purely quantum regime. At the Fano resonance this is exactly what happens, i.e., RHS ofEq. 25 becom es 0 precisely due to the fact that $(1 + \frac{1}{2}) = 0$ at the Fano resonance (see Eq. 9). A lso note that although each term in the series decreases with energy, the sum does not decrease easily as the series is a divergent series. It goes as $\log N$] where N is the total num ber of terms in the series or the total num ber of evanescent m odes [11]. O ne can make the transverse width w ! 1 to create an in nite num ber of evanescent m odes and then one can see from Eq. 25 that the correction term goes to zero implying that FSR is exact in 2D. In real quantum wires, we have to truncate the series at som e value N . For any arbitrary number of evanescent modes, the correction term can be as large as $\frac{d_f}{dE}$ or [(GC)(E) (GC)(E)], making the two qualitatively and quantitatively di erent, except in a narrow energy regime glose to the upper band edge. At the upper band edge $n > 1 \frac{1}{2}$ diverge as the rst term in it (i.e., $\frac{22}{2k_2}$) diverges and hence RHS of Eq. 25 becom es 0.

IV. W IGNER DELAY TIME (W DT)

The fact that FSR becomes exact at the Fano resonance is very counterintuitive. FSR is similar to W DT and so it was also checked that W DT at the Fano resonance becomes exact [12]. The similarity between W DT and FSR can be seen from Eqs. 19 and 20.

$$\begin{array}{ccc} X & \frac{1}{4 i} [S^{Y} \frac{dS}{dE} & H C] = \end{array}$$

 $\sim \frac{d}{dE} \arg(S)$) is the W DT for particles transmitted from the th channel to the th channel and there are 5 fof such particles. O ne can choose $\sim = 1$. Here arg (S) = A rctan $\left[\frac{\text{Im } [S]}{\text{R e}[S]}\right]$. We have also seen that the LHS in Eq. 28 is the sem i-classical lim it of the LHS of Eq. 18 integrated over x⁰. So in the sem i-classical lim it, W D T tim es the num ber of particles involved gives the PDOS. It was shown in Ref. [8], that in the Fano regim ealso the WDT $\left(\frac{1}{2} \frac{1}{5} \int \frac{d}{dE} \arg(S)\right)$ gives the PDOS (1 (x)dx) exactly, in spite the fact that Fano resonance is a quantum phenom enon. This happens for single channel quantum wires as well as for multi channel quantum wires. Anotherway to see that the W DT is sem i-classical is that its derivation is based on non-dispersive wave-packets. Below we show how non-dispersive wave-packets are realized in the quantum regime of Fano resonance and as a result W D T becomes exact (that is W D T gives the PDOS correctly).

W e start by presenting a derivation of the W D T based on non-dispersive wave-packets. Let us consider an incident G aussian wave packet in 1D representing an ensem ble of non-interacting particles. a(k) is the weight of the kth Fourier component in the incident G aussian wave packet.

$$a(\mathbf{k})\exp[i\mathbf{k}\mathbf{x} \quad i\mathbf{w}t]d\mathbf{k} \quad (29)$$

A first the wave packet traverses a distance ${\tt L}$, its form will be

$$tr (x;t) = a(k)T (k)exp[ik (x + L) iw (t + t_0 + t)]dk$$
(30)

Here, T (k) is the transm ission am plitude of the potential in the region of length L. t_0 is the time that the wave packet would have taken if the potential was absent. $t_0 + t$ is the time that the wave packet takes in presence of the potential. If we go to the sem i-classical limit then we should get close to classical behavior that im plies

 $t_{r}(\mathbf{x};t)$ is also a Gaussian wave-packet like $i_{n}(\mathbf{x};t)$. From this one can derive W DT.Normally, T (k) is com – plex and energy dependent. This is the essential cause of dispersion. The weight of the kth component in the transm itted wavepacket are a (k)T (k) and hence tr is no longer a G aussian wave packet. If T (k) is a real number, then the dispersion will be like a free particle as k and w in tr are identical to that of a free particle ($w = \frac{-k^2}{2m}$). One simple example where this happens is when the incident energy is much sm aller than the potential height, wherein one gets T (k) ! O and R (k) ! -1. In this case R (k) is real. One model the W D T

$$t = -\frac{d}{dE} \arg(R) = \frac{d}{dw} \arg(R)$$
(31)

and it connectly gives the PDOS (that is $\frac{1}{2} \Re f_{dE}^2 \arg(\mathbb{R}) = (x)dx$).

This explains why FSR is exact in case of single channel Fano resonance where the particle is completely relected back due to an elective potential that is in nite. At the single channel Fano resonance R (k) = 1 and W DT give the correct PDOS. This also shows that the correctness of W DT and hence FSR at Fano resonance is always true in single channel quantum wires. It requires the presence of a transm ission zero and that is always there for all potentials that support a Fano resonance. But the correctness of FSR or W DT does not only occur in case of single channel quantum wires where R (k) = -1 as in sem i-classical limit, but it also happens in multi channel quantum wires where $\Re_{11}(k) j \in 0$ and $J_{11}(k) j \in 0$. So how for such a system W DT or FSR remain exact?

In order to show how one can get non-dispersive wave packets in the presence of quantum scattering, we take clue from the kink-antikink solution of the Sine-Gordon equation. Suppose we have a delta function potential in a 2 channel quantum wire. Let us have four identical Gaussian wave packets incident on it along all possible channels. That means two will be incident from the left and two will be incident from the right. Among the two that are incident from the left, one will be in the st channel or in the fundam ental transverse m ode and one will be in the 2nd channel that is the st excited transverse mode. Sim ilarly for the two that are incident from the right. All these wave packets are scattered at the same time and we call this time t. A fler scattering, the resultant wave packet on the right in the fundam ental mode (say) and moving away from the potential and at a distance L from the delta function potential will be Ζ

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$$\sum_{tr}^{QW} = a_1 (k_1) T_{11} (k_1) \exp [ik_1 (x + L)] iw (t + t_0 + t_{T_{11}}) dk_1$$

$$a_2 (k_2) T_{21} (k_2) \exp[ik_1 (x + L) iw (t + t_0 + t_{T_{21}}) dk_2]$$

$$a_1 (k_1) R_{11} (k_1) \exp[ik_1 (x + L) iw (t + t_0 + t_{R_{11}}) dk_1$$

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+ $a_2 (k_2) R_{21} (k_2) exp [ik_1 (x + L) iw (t + t_0 + t_{R_{11}}] dk_2$ (32)

Here $t_0 + t_{T_{11}}$ is for example the time taken by a particle in going from st channel in the left lead to the rst channel on the right lead, and so on. One has to start with an in nitesim alpotential so that with a sm all probability a particle goes from channel 2 on left to channel 1 on the right with an in nitesimal f_{21} . And then by increasing the potential to its actual value, one can get actual $t_{T_{21}}$ etc. It is easy to show that $a_1(k_1) = a_1(k_1)$ and $a_2(k_2) = a_2(k_2)$. So FSR as well as WDT will be connect if $\begin{array}{c} \mathbb{Q} \ \mathbb{W} \\ \mathrm{tr} \end{array}$ is also a Gaussian wave packet. One way to get that is if T_{11} (k), T_{21} (k), R_{21} (k) and R_{11} (k) are simultaneously real. Because then the weight of the kth component is a real number times ai (k) and further those real num bers are com plim entary to each other and also sum m ed. That is if T_{11} (k) increases then T_{21} (k) decreases and the st two terms in Eq. 32 compensate each other and so on. One can also show that $T_{21} = R_{21}$, and $\arg(T_{21}) = \arg(R_{21}) = \arg(R_{11})$. In the following

gure we show that T_{11} , T_{21} , R_{21} and R_{11} are simultaneously real at the Fano resonance. Since they are real, their squares add up to make 1. So they are also complementary to each other and compensate each other. If T_{11} is small the R_{11} is large and so on. A ctually, all the phase shifts vary strongly with energy as is expected in a quantum regime, but the variations are around 0 and becoming exactly 0 at the Fano resonance.

O ne can check the outgoing wave packets in the other channels also. They all show sim ilar behavior at the Fano resonance. A lthough, the individual wave packets get strongly scattered, the four scatterings compensate each other in such a way that the outgoing waves are sim ilar to the incom ing waves. So the derivation of W D T holds good and so naturally the W D T also holds good. And then sum m ing overall the particlesm aking the wave packet, one naturally gets that FSR holds good. This provides a physical picture that helps us to understand why sem i-classical form ulas based on un-dispersed wave packets hold good in an extrem e quantum regim e. Sem iclassical form ulas are always m uch sim pler and easy to understand as it has classical analogies.

V. CONCLUSION

For larger systems, that is when the sample size is larger than the inelastic mean free path, it has been argued that the scattering matrix approach do not take into account the conservation of charge [22]. FSR can break down due to non-conservation of charge [23]. In this work we show that even form esoscopic systems, that is when sample size is smaller than inelastic mean free path, although charge is conserved, the scattering matrix approach does not give the DOS exactly. In a quantum wire, the correction term due to the evanescent modes is quite complicated and it is not possible to make any general statem ent about it like correction term is negligible in sem i-classical regime and large in quantum regimes. Q uite counter intuitively, the correction term in Eq. 25, becomes 0 at the Fano resonance as a result of which the FSR becom es exact. W e do not know of any system where this correction term can become exactly 0. We have shown that in single channel quantum wire, this is true for all potential that exhibit a Fano resonance as it only requires the presence of a transm ission zero. W e have also taken a scatterer in a multi channel quantum wire that has Fano resonance, wherein all the S s are non zero and also strongly energy dependent. But the correction term is once again exactly 0 m aking the FSR exact at the Fano resonance. W e provide a physical understanding of this based on non-dispersive wave packets that are crucial for the derivation of sem i-classical formulas like FSR and W DT. This gives us a general prescription to check for a given Fano resonance in a multichannel quantum wire, if sem i-classical form ulas will be exact or not. A lthough, the quantum mechanical scattering can strongly disperse the di erent partial waves, the resultant of all possible partial waves in the Hilbert space and their scattering compensate each other in such a way that the resultant wave-packet is un-dispersed.

The advantage of using FSR to know the DOS of a system has certain advantages. It makes it un-necessary to

nd the local wave-functions inside a scatterer and also removes the problem of integrating the LDOS to nd the DOS. Also FSR is expected to work in presence of electron-electron interactions [24]. An easy way to see this is to consider the Kohn-Sham theorem [25], which essentially means that an electron passing through an interacting system, actually passes through a one body e ective potential that accounts for exchange and correlation e ects exactly.

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VII. APPENDIX

Let us calculate the DOS (E) for the system in Fig. 2. We rst consider the electron incident from the left (as shown in Fig. 2), with incident wave vector k. The PDOS in this case is

⁽¹⁾ (E) =
$$\frac{1}{hjvj} \int_{1}^{Z_{1}} jae^{ikx} + be^{-ikx} \int dx$$

+ $\int_{1}^{Z_{1}} je^{ikx} + Re^{-ikx} \int dx + \int_{1}^{Z_{1}} Te^{ikx} \int dx$ (33)

T is the same whether incident from left or incident from right. We next consider the electron incident from the right, with incident wave vector k. The PDOS in this

case is

⁽²⁾ (E) =
$$\frac{1}{h j v j} \int_{1}^{Z} a e^{-ikx} + b e^{ikx} f dx$$

Therefore DOS is given by

$$(\mathbf{E}) = {}^{(1)}(\mathbf{E}) + {}^{(2)}(\mathbf{E}) = \frac{1}{hv} \left[2 \right]_{1}^{L_{1}} d\mathbf{x} + 2^{0}$$

$$+ R {}^{Z_{1}} \cos \left[2kx \right] d\mathbf{x} + iR {}^{Z_{1}} \sin \left[2kx \right] d\mathbf{x}$$

$$+ R {}^{Z_{1}} \cos \left[2kx \right] d\mathbf{x} + iR {}^{Z_{1}} \sin \left[2kx \right] d\mathbf{x}$$

$$+ R {}^{Z_{1}} \cos \left[2kx \right] d\mathbf{x} + iR {}^{Z_{1}} \sin \left[2kx \right] d\mathbf{x}$$

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$$+ R {}^{Z_{1}} \cos \left[2kx \right] d\mathbf{x} + iR {}^{Z_{1}} \sin \left[2kx \right] d\mathbf{x}$$

$$+ R {}^{Z_{1}} \cos \left[2kx \right] d\mathbf{x} + iR {}^{Z_{1}} \sin \left[2kx \right] d\mathbf{x}$$

$$(35)$$

where

$${}^{0} = \int_{1}^{Z} e^{ikx} + be^{-ikx} \int dx = \frac{Z}{1} dx = \frac{hv}{2} [({}^{GC} (E)) {}^{GC} (E)]$$
(36)

The inde nite integrals on $\sin [k]$ and $\cos [k]$ can be done by breaking them up in exponential functions to give

$$(E) = \frac{1}{hv} \begin{bmatrix} Z & 1 \\ D & 1 \end{bmatrix} dx$$

+ 2⁰
$$\frac{\sin [2k]}{k}$$
 (R + R) + $\frac{\cos [2k]}{k}$ (iR iR)] (37)

Thus we have proved that

(E)
$$_{0}$$
 (E) = GC (E) $^{GC}_{0}$ (E)

$$\frac{\sin [2k1]}{k} (R + R) + \frac{\cos [2k1]}{k} (iR - iR)$$
 (38)

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Figure Captions

Fig. 1. A grand canonical system, extending from A to B, connected to two reservoirs on two sides with ideal leads.

Fig. 2. A realization of the system shown in Fig. 1 in one dimensions.

Fig. 3. Here $G = 1 + P_{=n}^{P_{=1}} \frac{1}{2k}$, that is the LHS of Eq. 9. It is shown by the solid line. When it crosses the energy-axis, then we get a bound state. arg (T_{11}) (dashed curve)

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and arg (R $_{11}$) (dotted curve) become simultaneously 0 at the bound state or at the Fano resonance. This implies

 T_{11} , R $_{11}$, T_{21} and R $_{21}$ are simultaneously real at the Fano resonance.

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